

SiC Schottky Barrier Diode

V_R	650V		
I _F	12A		
Q_C	18nC		

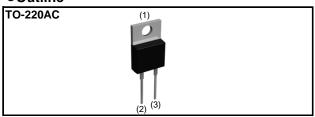
Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

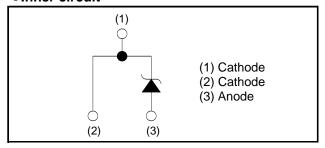
Construction

Silicon carbide epitaxial planer type

Outline



•Inner circuit



Packaging specifications

Туре	Packaging	Tube
	Reel size (mm)	-
	Tape width (mm)	-
	Basic ordering unit (pcs)	50
	Taping code	С
	Marking	SCS212AG

● Absolute maximum ratings (Ti = 25°C)

Parameter	Symbol	Value	Unit	
Reverse voltage (repetitive peak)	V_{RM}	650	V	
Reverse voltage (DC)	V _R	650	V	
Continuous forward current	I _F	12* ¹	А	
		45* ²	А	
Surge no repetitive forward current	I _{FSM}	170* ³	А	
		36* ⁴	А	
Repetitive peak forward current	I _{FRM}	49* ⁵	А	
Total power disspation	P _D	93* ⁶	W	
Junction temperature	Tj	175	°C	
Range of storage temperature	Tstg	-55 to +175	°C	

^{*1} Tc=134°C *2 PW=8.3ms sinusoidal, Tj=25°C *3 PW=10μs square, Tj=25°C

^{*4} PW=8.3ms sinusoidal, Tj=150°C *5 Tc=100°C, Tj=150°C, Duty cycle=10% *6 Tc=25°C

●Electrical characteristics (Tj = 25°C)

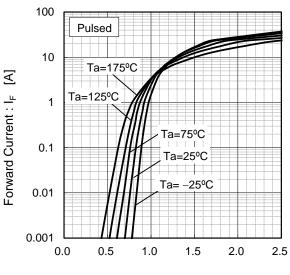
Parameter	Symbol	Conditions	Values			Linit
		Conditions	Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =0.24mA	600	-	-	V
Forward voltage	V _F	I _F =12A,Tj=25°C	-	1.35	1.55	V
		I _F =12A,Tj=150°C	-	1.55	-	V
		I _F =12A,Tj=175°C	-	1.63	-	V
Reverse current	I _R	V _R =600V,Tj=25°C	-	2.4	240	μΑ
		V _R =600V,Tj=150°C	-	36	-	μΑ
		V _R =600V,Tj=175°C	-	84	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	438	-	pF
		V _R =600V,f=1MHz	-	44	-	pF
Total capacitive charge	Qc	V _R =400V,di/dt=350A/μs	-	18	-	nC
Switching time	tc	V _R =400V,di/dt=350A/μs	-	16	-	ns

●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	$R_{th(j-c)}$	-	1	1.3	1.6	°C/W

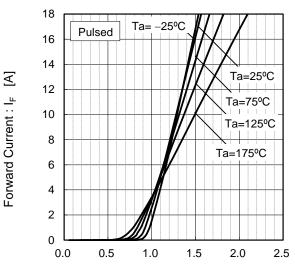
•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics



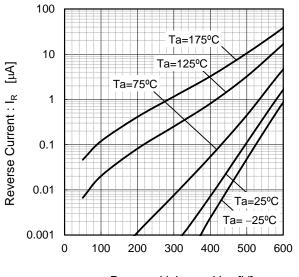
Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics



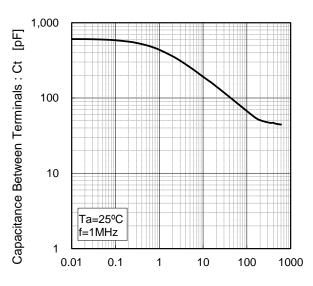
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R-Ct Characteristics



Reverse Voltage : V_R [V]

•Electrical characteristic curves

Fig.5 Thermal Resistance vs. Pulse Width

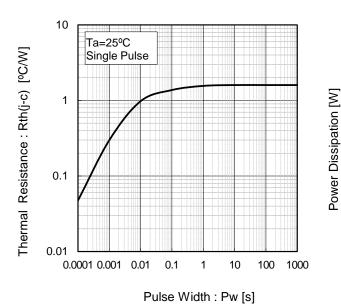
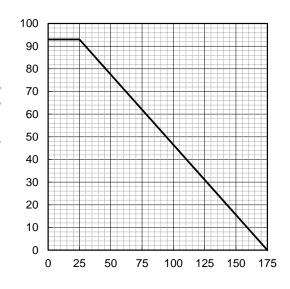
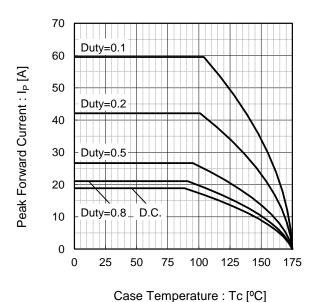


Fig.6 Power Dissipation



Case Temperature : Tc [°C]

Fig.7 Ip-Tc Derating Curve



Power Dissipation [W]

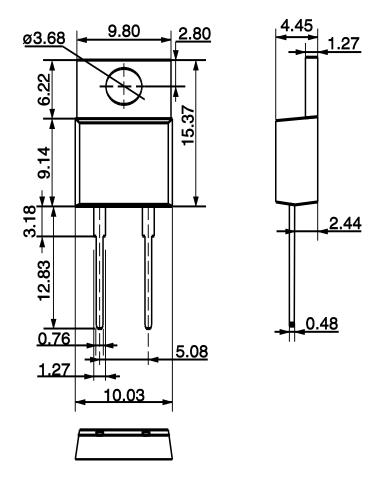
60
50
Duty=0.2
Duty=0.1
40
30
D.C.
20
Duty=0.8
10
0
5
10
15
20

Fig.8 Io-Pf Characteristics

Average Rectified Forward Current : Io [A]

●Dimensions (Unit:mm)

TO-220AC



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